TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (DARLINGTON)

2SD2584

HIGH POWER SWITCHING APPLICATIONS

HAMMER DRIVE, PULSE MOTOR DRIVE APPLICATIONS

High DC Current Gain

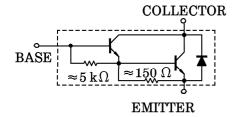
: $h_{FE} = 2000$ (Min.) ($V_{CE} = 3 V$, $I_{C} = 3 A$)

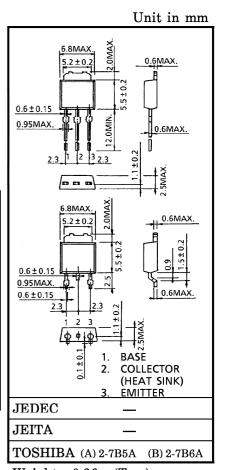
• Low Saturation Voltage : $V_{CE (sat)} = 1.5 \text{ V (Max.)} (I_C = 3 \text{ A})$

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERIST	SYMBOL	RATING	UNIT		
Collector-Base Voltage	v_{CBO}	120	V		
Collector-Emitter Voltage	v_{CEO}	100	V		
Emitter-Base Voltage	$ m v_{EBO}$	6	V		
Collector Current	DC	$I_{\mathbf{C}}$	7	A	
	Pulse	I_{CP}	10		
Base Current	$I_{\mathbf{B}}$	0.7	A		
Collector Power	$Ta = 25^{\circ}C$	$P_{\mathbf{C}}$	1.5	w	
Dissipation	$Tc = 25^{\circ}C$	10	20		
Junction Temperature		T_{j}	150	°C	
Storage Temperature Range		$\mathrm{T_{stg}}$	-55~150	°C	

EQUIVALENT CIRCUIT





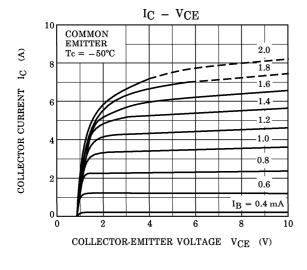
Weight: 0.36 g (Typ.)

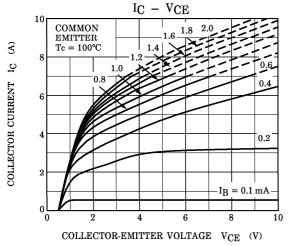
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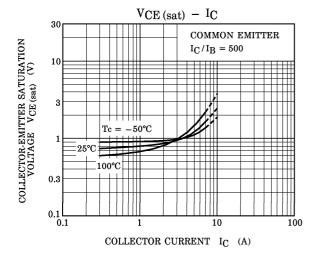
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

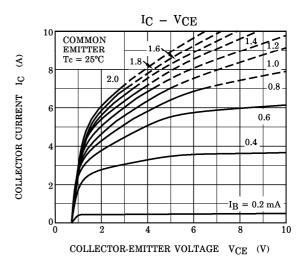
CHARA	CTERISTIC	SYMBOL	TEST CONDITION		TYP.	MAX.	UNIT	
Collector Cut-off Current I _{CBO} V _{CB} = 100		$V_{CB} = 100 V, I_{E} = 0$	_	_	100	μ A		
Emitter Cut-off Current		$I_{ m EBO}$	$V_{EB} = 6 V, I_{C} = 0$	0.75	_	3.0	mA	
Collector-Emitter Breakdown Voltage		V (BR) CEO	$I_{C} = 50 \text{ mA}, I_{B} = 0$	100	_	_	V	
DC Current Gain		h _{FE (1)}	$V_{CE} = 3 V, I_{C} = 3 A$	2000	_	15000		
		h _{FE} (2)	$V_{CE} = 3 \text{ V}, I_{C} = 6 \text{ A}$	1000	_	_		
Collector-Emitter Saturation Voltage		V _{CE} (sat)	$I_{\mathrm{C}}=3~\mathrm{A},~I_{\mathrm{B}}=6~\mathrm{mA}$	_	0.9	1.5	V	
Base-Emitter Saturation Voltage		V _{BE (sat)}	$I_{\mathrm{C}}=3~\mathrm{A},~I_{\mathrm{B}}=6~\mathrm{mA}$	_	1.5	2.0	V	
Switching Time	Turn-on Time	t _{on}	OUTPUT 20 \(\mu\)s \(\overline{\Implies}\) G		0.3	_		
	Storage Time	$t_{ ext{stg}}$	I _{B1} PUT I _{B2}	_	5.1	_	μ s	
	Fall Time	t_f	$I_{B1} = -I_{B2} = 6 \text{ mA}, V_{CC} = 45 \text{ V}$		0.6	_		

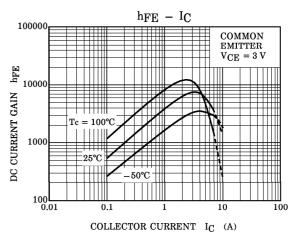
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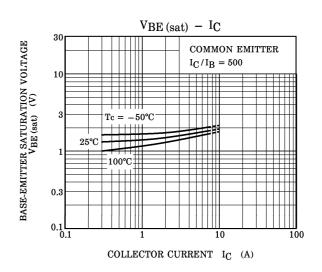




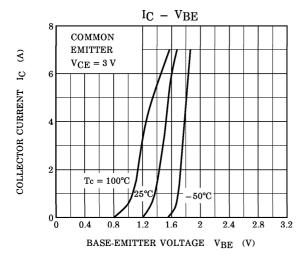


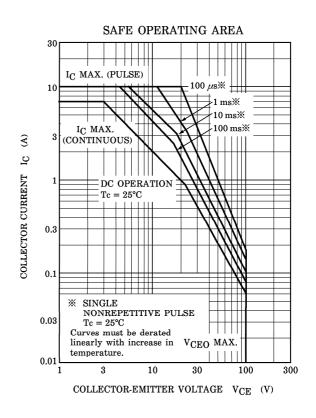






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